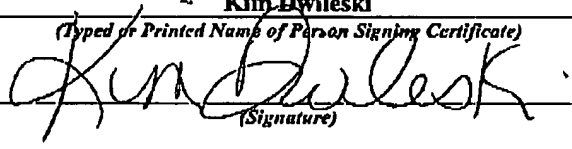


<b>CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)</b> Applicant(s): Ng et al.			Docket No. END920030086US1	
Application No. 10/713,227	Filing Date 11/13/2003	Examiner Novacek, Christy L.	Group Art Unit 2822	
Invention: METHOD AND STRUCTURE TO USE AN ETCH RESISTANT LINER ON TRANSISTOR GATE STRUCTURE TO ACHIEVE HIGH DEVICE PERFORMANCE				
<b>RECEIVED</b> CENTRAL FAX CENTER SEP 26 2005				
I hereby certify that this <u>Amendment (15 pages)</u> (Identify type of correspondence) is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>571-273-8300</u> ) on <u>9/26/2005</u> (Date)				
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**Docket No.: END920030086US1**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: Hung Y. Ng

)Examiner: Novacck, Christy L.

)

Serial No.: 10/713,227

)Art Unit: 2822

)

Filing Date: 11/13/2003

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Title: METHOD AND STRUCTURE TO USE AN ETCH RESISTANT LINER ON  
TRANSISTOR GATE STRUCTURE TO ACHIEVE HIGH DEVICE PERFORMANCE

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Commissioner For Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Sir:

In response to the Office Action mailed July 1, 2005, please amend the above-identified  
patent application as follows: